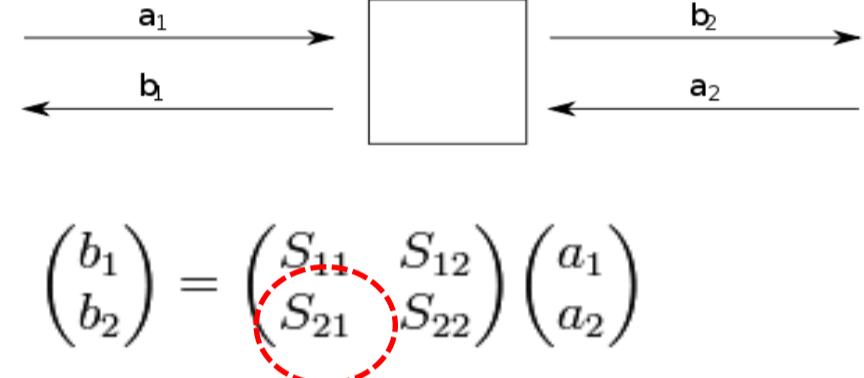


Bias-T (BT-01)

max applied voltage	1-2kV (depends on version)
leakage	<500 nA @ 1 kV
frequency range	low end hi end
input impedance	<100 kHz >2000 MHz
output impedance	~50 Ω ~50 Ω
Physical measures [cm]	(LxWxD) 7x5x1.5



Response function of the amplifier - S parameters



a1 - input signal
b1 - reflected signal
b2 - output signal

Comparison with other vendors (IR - TCT signal in 300 μm fully depleted silicon p-n sample)

